

## Amendments to the Specification

Please replace the paragraph beginning at page 5, line 21, with the following rewritten paragraph:

-- In another aspect of the invention there is provided a light-emitting device, comprising a substrate and a first electrically conductive layer defining forming an anode electrode layer on the substrate. The device includes a hole transport layer on said anode electrode layer, a layer of a light emissive material on said hole transport layer, an electron transport layer comprising fullerenes located on said layer of a light emissive material, and a second electrically conductive layer defining forming a cathode electrode layer on the electron transport layer. The device includes a layer comprising a light emissive material interposed between the anode electrode layer and the electron transport layer, a first interfacial layer located between said layer of light emissive material and said electron transport material for improving electrical contact between said layer of light emissive material and said layer of electron transport material and a second interfacial layer located between said electron transport layer and said second electrically conductive layer, said interfacial layer comprising a fluoride compound for providing an Ohmic contact between said cathode electrode layer and said fullerene layer.

Please replace the paragraph beginning on page 6, line 5, with the following rewritten paragraph:

In this aspect of the invention the device may include a hole transport layer interposed between the anode electrode layer and the light emissive material. The hole transport layer may be comprised of organic molecules which conduct holes.

Please replace the paragraph beginning at page 6, line 9 with the following rewritten paragraph:

~~In this aspect of the invention the device may include an interfacial layer interposed between the layer comprising a fullerene and the electrically conductive layer defining a cathode electrode with the material of the interfacial layer being selected so that the interfacial layer makes Ohmic contact with the fullerene layer. The interfacial layer may comprise a fluoride compound and may be an alkaline fluoride compound. The fluoride compound may be calcium fluoride (CaF<sub>2</sub>).~~ --

Please replace the paragraph beginning at page 6, line 14, with the following rewritten paragraph:

-- ~~There may also be an a~~ In this aspect of the invention, the first interfacial layer may be a lithium fluoride (LiF) layer of thickness from about 0.2nm to about 3nm located between the electron transport layer comprising fullerenes and the layer of light-emissive material. --

Please replace the paragraph beginning at page 6, line 17, with the following rewritten paragraph:

-- ~~There may also be an a~~ The first interfacial layer interposed between the layer comprising a fullerene and the light-emissive layer may be made from a material which blocks holes whereby the hole blocking layer blocks or prevents holes from leaking into the fullerene layer. --

Please replace the paragraph beginning at page 11, line 22, with the following rewritten paragraph:

--Referring to Figure 3, an EL device 18 has been constructed to demonstrate the integration of a fullerene layer into a typical small organic molecule based device of the type disclosed in United States Patent No. 4,356,429. The device 18 comprises a substrate 20, a conductive anode electrode layer 30 for hole injection, a hole transport layer 40 for hole transport, a light emissive or light-emission layer 50 capable of emitting light formed on the hole transport layer 40, a fullerene layer 60 formed on the light-emission layer 50, an outer conductive cathode layer 90 and an interfacial contact layer 80 sandwiched between fullerene layer 60 and cathode layer 90 which makes Ohmic contact with fullerene layer 60 and cathode layer 90. An optional cathode capping layer 100 made of a dielectric, such as Si oxides and nitrides, may be deposited on the cathode layer 90. The protective coating may also be a fullerene layer. --